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Inclosure Material: Metal Overall Length: Between 0.240 inches and 0.260 inches Terminal Length: 0.500 inches Overall Diameter: Between 0.335 inches and 0.370 inches Function For Which Designed:

Switching

Internal Configuration:

Junction contact-darlington connected

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-5

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Terminal

Terminal Circle Diameter:

0.200 inches

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

50.0 collector to base voltage, dc and 40.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage, dc

Current Rating Per Characteristic:

Between 500.00 milliamperes source cutoff current and 1.00 amperes source cutoff current

Power Rating Per Characteristic:

6.0 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Test Data Document:

80063-sm-a-726667 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

3 pin

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

